NSN 5962-01-340-2104

Memory Microcircuit - Page 1 of 1



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Features Provided:

Programmable and monolithic and electrostatic sensitive

Inclosure Material:

Ceramic

Inclosure Configuration:

Leadless flat pack

Output Logic Form:

Complementary-metal oxide-semiconductor logic

Terminal Surface Treatment:

Solder

Memory Device Type:

Prom

Terminal Type And Quantity:

28 leadless

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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